

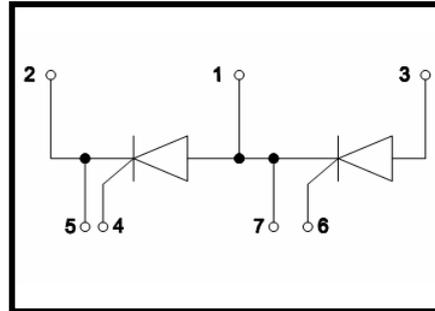
Features

- Isolation voltage 3500 V~
- Industrial Standard Package
- High Surge Capability
- Glass Passivated Chips
- Simple Mounting
- Electrically Isolated by DBC Ceramic



Applications

- DC Motor Control and Drives
- Battery Charges
- Welders
- Power Converters
- Lighting Control
- Heat and Temperature Control



Advantages

- Space and weight savings
- Improved temperature and power cycling

ABSOLUTE MAXIMUM RATINGS

T_C=25°C unless otherwise specified

Symbol	Test Condition	Value	Unit
V _{RRM} /V _{DRM}		1600	V
I _{T(AV)}	T _C =85°C, 180° conduction, half sine wave;	40	A
I _{T(RMS)}	as AC switch;	100	A
I _{TSM}	T _J =45°C, t=10ms (50Hz), sine, V _R =0;	850	A
	T _J =45°C, t=8.3 ms (60Hz), sine, V _R =0;	890	
	T _J =45°C, t=10ms (50Hz), sine, V _R =V _{RRM} ;	715	
	T _J =45°C, t=8.3 ms (60Hz), sine, V _R = V _{RRM} ;	750	
i ² _t	T _J =45°C, t=10ms (50Hz), sine, V _R =0;	3.61	K A ² s
	T _J =45°C, t=8.3 ms (60Hz), sine, V _R =0;	3.3	
	T _J =45°C, t=10ms (50Hz), sine, V _R =V _{RRM} ;	2.56	
	T _J =45°C, t=8.3 ms (60Hz), sine, V _R = V _{RRM} ;	2.33	
I _{DRM} /I _{RRM}	T _J =130°C, V _D =V _R =1600V, gate open circuit;	15	mA
dV/dt	T _J =130°C, exponential to 67% rated V _{DRM}	500	V/us
V _{ISOL}	50Hz, all terminals shorted, t=1s, I _{ISOL} ≤1mA ;	3500	V~
T _J	Max. junction operating temperature range	-40~125	°C
T _{STG}	Max. storage temperature range	-40~125	°C

ELECTRICAL CHARACTERISTICS $T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Test Condition	Min.	Typ.	Max.	Unit
V_{TO}	$16.7\% \times p \times I_{AV} < I < p \times I_{AV}, T_J = 130^{\circ}\text{C};$			0.88	V
	$I > p \times I_{AV}, T_J = 130^{\circ}\text{C};$			0.91	V
r_t	$16.7\% \times p \times I_{AV} < I < p \times I_{AV}, T_J = 130^{\circ}\text{C};$			5.9	m Ω
	$I > p \times I_{AV}, T_J = 130^{\circ}\text{C};$			5.74	m Ω
I_H	$V_{AK} = 6\text{V}$, resistive load;			200	mA
I_L	Anode supply =6V, resistive load=1 Ω , gate pulse =10V, 100us;			400	mA
V_{TM}	$I_{TM} = 141\text{A}$, $t_d = 10\text{ ms}$, half sine			1.81	V
P_{GM}	$t_p \leq 5\text{ms}$, $T_J = 125^{\circ}\text{C};$			10	W
$P_{GM(AV)}$	$f = 50\text{Hz}$, $T_J = 125^{\circ}\text{C};$			2.5	W
I_{GM}	$t_p \leq 5\text{ms}$, $T_J = 125^{\circ}\text{C};$			2.5	A
$-V_{GT}$				10	V
V_{GT}	$V_A = 6\text{V}$, $R_A = 1\Omega$, $T_J = -40^{\circ}\text{C};$			4	V
	$V_A = 6\text{V}$, $R_A = 1\Omega;$			2.5	
	$V_A = 6\text{V}$, $R_A = 1\Omega$, $T_J = 125^{\circ}\text{C};$			1.7	
I_{GT}	$V_A = 6\text{V}$, $R_A = 1\Omega$, $T_J = -40^{\circ}\text{C};$			270	mA
	$V_A = 6\text{V}$, $R_A = 1\Omega;$			150	
	$V_A = 6\text{V}$, $R_A = 1\Omega$, $T_J = 125^{\circ}\text{C};$			80	
V_{GD}	$V_{AK} = V_{DRM}$, $T_J = 125^{\circ}\text{C}$			0.25	V
I_{GD}				6	mA
di/dt	$T_J = 25^{\circ}\text{C}$, $V_D = 0.67V_{DRM}$, $I_{TM} = 345\text{A}$, $I_g = 500\text{mA}$, $tr < 0.5\ \mu\text{s}$, $tp > 6\ \mu\text{s}$			150	A/us

THERMAL AND MECHANICAL CHARACTERISTICS $T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Test Condition	value	Unit
R_{thjc}	DC operation, per junction;	0.5	K/W
R_{THCS}	Mounting surface smooth, flat and greased, per junction	0.12	K/W
Md	Mounting torque(M5)	3 to 5	N·m
	Terminal connection torque(M5)		
Weight	Typical value	105	g

Characteristic curves

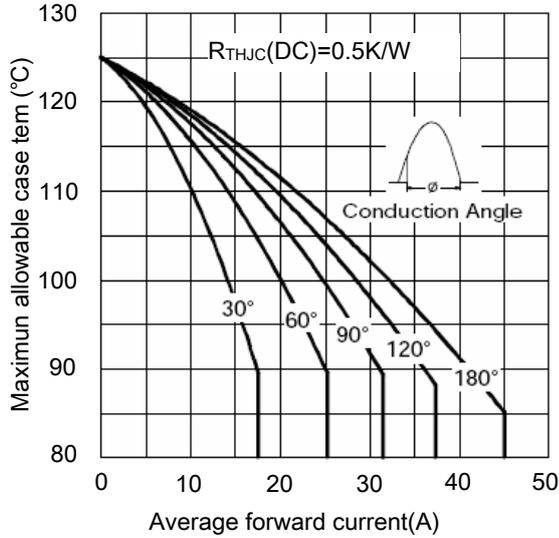


Figure 1. current rating characteristics

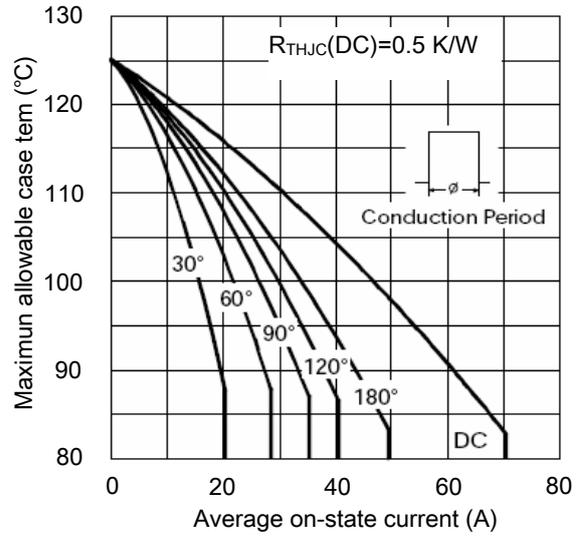


Figure 2. current rating characteristics

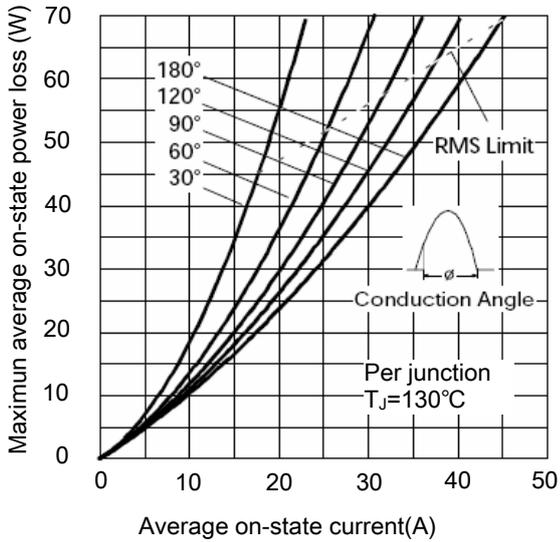


Figure 3. on-state power loss characteristics

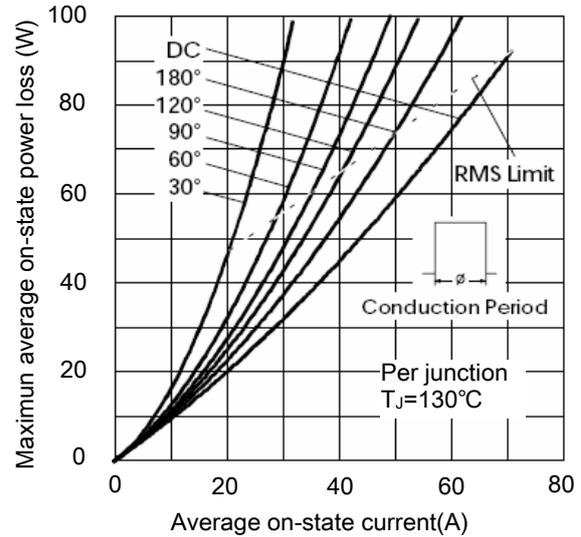


Figure 4. on-state power loss characteristics

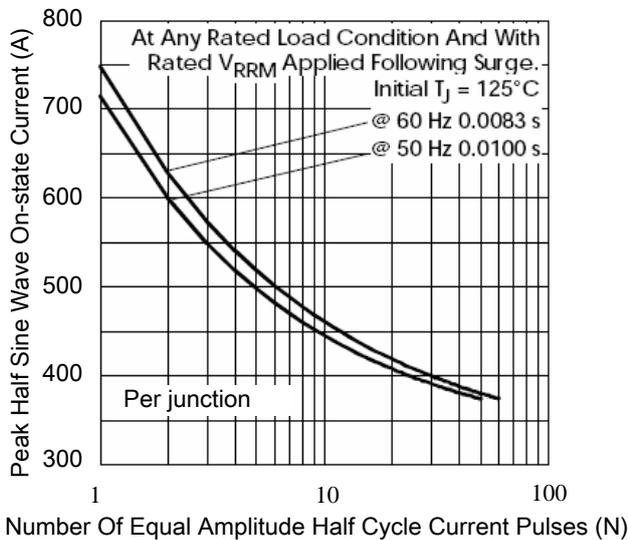


Figure 5. Maximum Non-Repetitive Surge Current

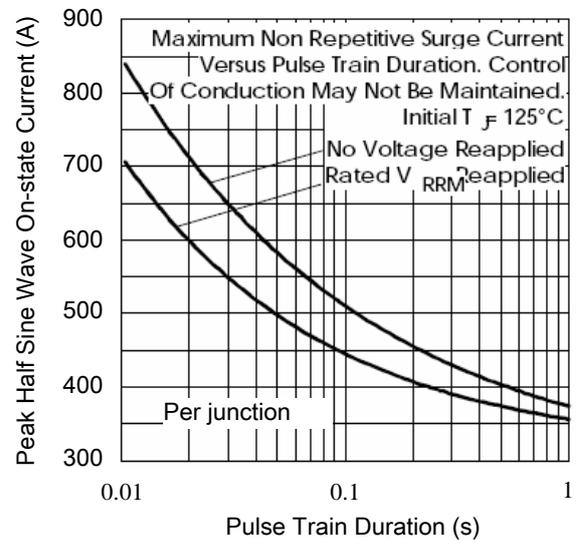


Figure 6. Maximum Non-Repetitive Surge Current

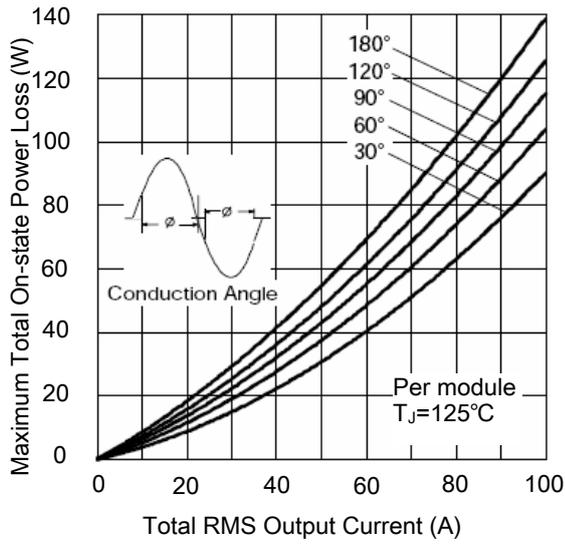


Figure 7. On-State Power Loss Characteristics-1

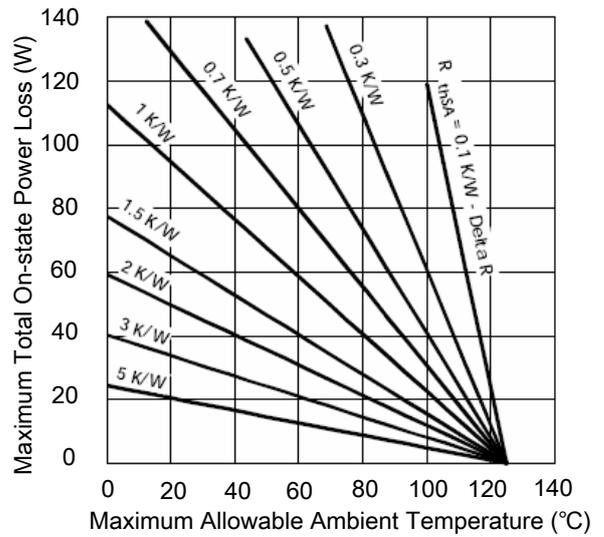


Figure.8 On-State Power Loss Characteristics-2

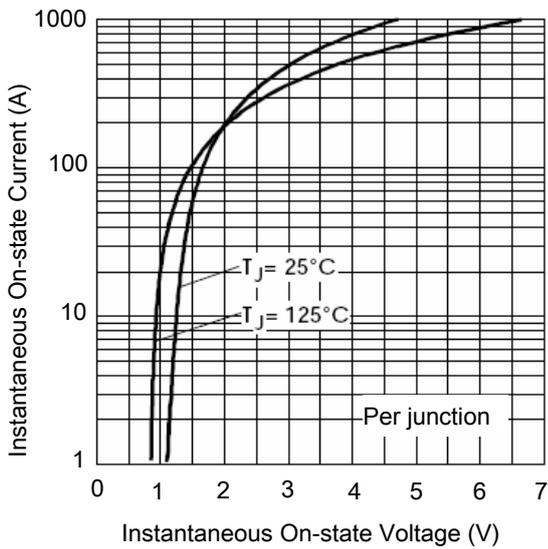


Figure.9 On State Voltage Drop Characteristics

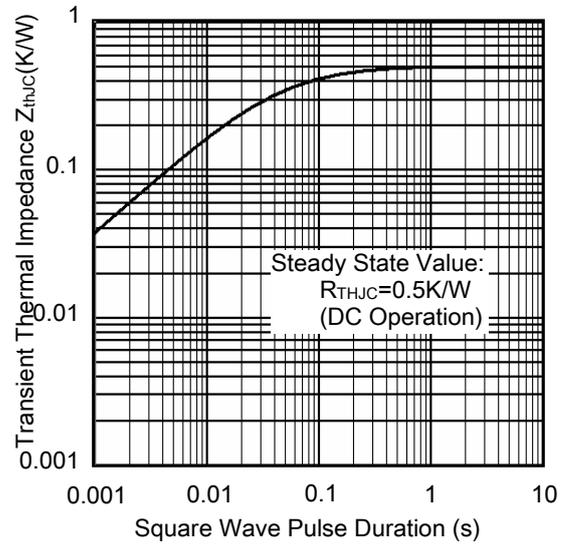


Figure.10 Thermal Impedance ZthJC Characteristics

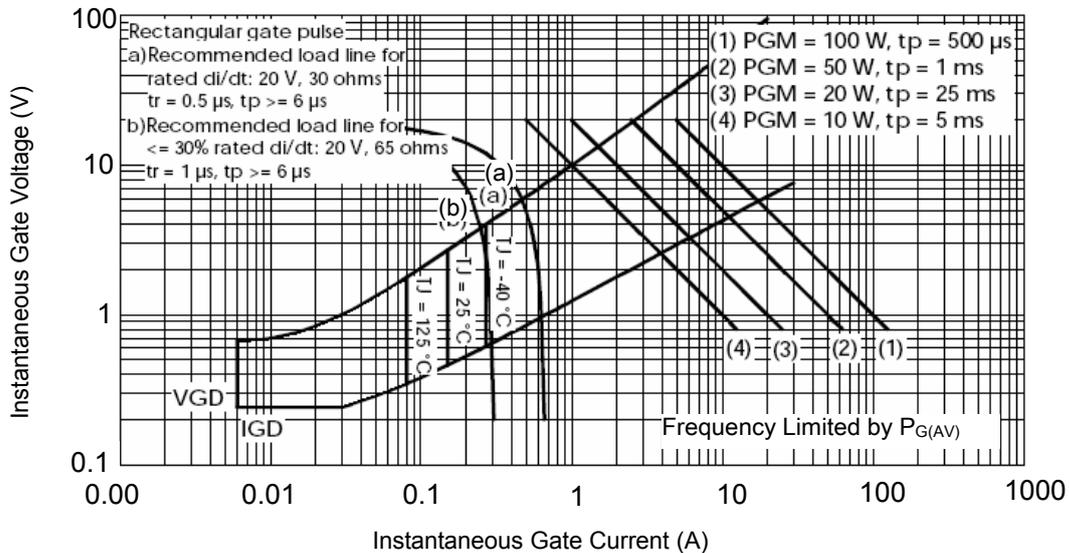


Figure.11 Gate Characteristics

Package Outline (Dimensions in mm)